

# TC74LCX04F/FN/FS

## TENTATIVE DATA

### LOW VOLTAGE HEX INVERTER WITH 5V TOLERANT INPUTS AND OUTPUTS

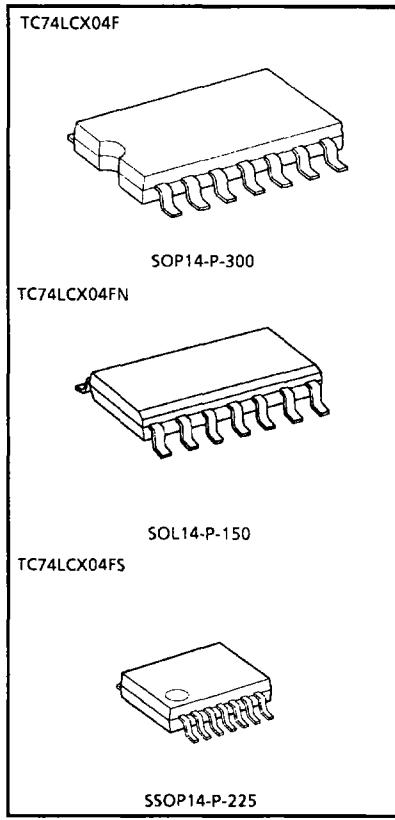
The TC74LCX04 is a high performance CMOS INVERTER. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3V) V<sub>CC</sub> applications, but it could be used to interface to 5V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

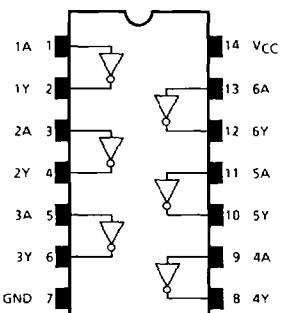
#### FEATURES

- Low voltage operation : V<sub>CC</sub> = 2.0~3.6V
- High speed operation : t<sub>pd</sub> = 5.2ns (Max.)  
(V<sub>CC</sub> = 3.0~3.6V)
- Output current : |I<sub>OH</sub>| / |I<sub>OL</sub>| = 24mA (Min.)  
(V<sub>CC</sub> = 3.0V)
- Latch-up performance : ± 500mA
- Available in JEDEC SOP, EIAJ SOP and SSOP
- Power down protection is provided on all inputs and outputs.
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 04 type.



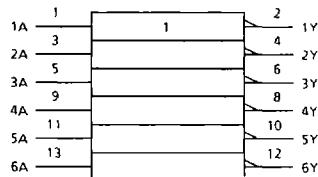
Weight    SOP14-P-300 : 0.18g (Typ.)  
            SOL14-P-150 : 0.12g (Typ.)  
            SSOP14-P-225 : 0.07g (Typ.)

## PIN ASSIGNMENT



(TOP VIEW)

## IEC LOGIC SYMBOL



## TRUTH TABLE

INPUTS	OUTPUTS
A	Y
L	H
H	L

## MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Power Supply Voltage	V <sub>CC</sub>	- 0.5~7.0	V
DC Input Voltage	V <sub>IN</sub>	- 0.5~7.0	V
DC Output Voltage	V <sub>OUT</sub>	- 0.5~7.0 (Note 1)	V
		- 0.5~V <sub>CC</sub> + 0.5 (Note 2)	
Input Diode Current	I <sub>IK</sub>	- 50	mA
Output Diode Current	I <sub>OK</sub>	± 50 (Note 3)	mA
DC Output Current	I <sub>OUT</sub>	± 50	mA
Power Dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /Ground Current	I <sub>CC</sub> /I <sub>GND</sub>	± 100	mA
Storage Temperature	T <sub>stg</sub>	- 65~150	°C

(Note 1) V<sub>CC</sub>=0V(Note 2) High or Low State. I<sub>OUT</sub> absolute maximum rating must be observed.(Note 3) V<sub>OUT</sub><GND, V<sub>OUT</sub>>V<sub>CC</sub>

## RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V <sub>CC</sub>	2.0~3.6	V
		1.5~3.6 (Note 4)	
Input Voltage	V <sub>IN</sub>	0~5.5	V
		0~5.5 (Note 5)	
Output Voltage	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 6)	V
		±24 (Note 7)	
Output Current	I <sub>OH</sub> /I <sub>OL</sub>	±12 (Note 8)	mA
		-40~85	
Operating Temperature	T <sub>opr</sub>	0~10 (Note 9)	°C
Input Rise And Fall Time	d <sub>t</sub> /d <sub>v</sub>	ns/V	

(Note 4) Data Retention Only

(Note 5) V<sub>CC</sub> = 0V

(Note 6) High or Low State

(Note 7) V<sub>CC</sub> = 3.0~3.6V(Note 8) V<sub>CC</sub> = 2.7~3.0V(Note 9) V<sub>IN</sub> = 0.8~2.0V, V<sub>CC</sub> = 3.0V

## ELECTRICAL CHARACTERISTICS

DC characteristics (Ta = -40~85°C)

PARAMETER		SYMBOL	TEST CONDITION	V <sub>CC</sub> (V)	MIN.	MAX.	UNIT	
Input Voltage	"H" Level	V <sub>IH</sub>		2.7~3.6	2.0	—	V	
	"L" Level	V <sub>IL</sub>		2.7~3.6	—	0.8		
Output Voltage	"H" Level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -100μA	2.7~3.6	V <sub>CC</sub> - 0.2	V	
				I <sub>OH</sub> = -12mA	2.7	2.2		
				I <sub>OH</sub> = -18mA	3.0	2.4		
				I <sub>OH</sub> = -24mA	3.0	2.2		
	"L" Level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 100μA	2.7~3.6	—	V	
				I <sub>OL</sub> = 12mA	2.7	—		
				I <sub>OL</sub> = 16mA	3.0	—		
				I <sub>OL</sub> = 24mA	3.0	—		
Input Leakage Current	I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		2.7~3.6	—	±5.0	μA	
Power Off Leakage Current	I <sub>OFF</sub>	V <sub>IN</sub> /V <sub>OUT</sub> = 5.5V		0	—	10.0	μA	
Quiescent Supply Current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7~3.6	—	10.0	μA	
		V <sub>IN</sub> /V <sub>OUT</sub> = 3.6~5.5V		2.7~3.6	—	±10.0		
Increase in I <sub>CC</sub> Per Input	ΔI <sub>CC</sub>	V <sub>IH</sub> = V <sub>CC</sub> - 0.6V		2.7~3.6	—	500	μA	

AC characteristics ( $T_a = -40\sim85^\circ C$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	MIN.	TYP	UNIT
Propagation Delay Time	$t_{pLH}$	(Fig.1, 2)	2.7	—	6.0	ns
	$t_{pHL}$		$3.3 \pm 0.3$	1.5	5.2	
Output To Output Skew	$ t_{osLH} $	(Note 10)	2.7	—	—	ns
	$ t_{osHL} $		$3.3 \pm 0.3$	—	1.0	

(Note 10) Parameter guaranteed by design.

$$(|t_{osLH}| = |t_{pLHm} - t_{pLHn}|, |t_{osHL}| = |t_{pHLm} - t_{pHLn}|)$$

DYNAMIC SWITCHING CHARACTERISTICS ( $T_a = 25^\circ C$ , Input  $t_r = t_f = 2.5\text{ns}$ ,  $C_L = 50\text{pF}$ ,  $R_L = 500\Omega$ )

PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	TYP	UNIT
Quiet Output Maximum Dynamic $V_{OL}$	$V_{OLP}$	$V_{IH} = 3.3V, V_{IL} = 0V$	3.3	TBD	V
Quiet Output Minimum Dynamic $V_{OL}$	$ V_{OLV} $	$V_{IH} = 3.3V, V_{IL} = 0V$	3.3	TBD	V

CAPACITIVE CHARACTERISTICS ( $T_a = 25^\circ C$ )

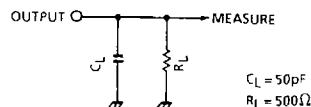
PARAMETER	SYMBOL	TEST CONDITION	$V_{CC}$ (V)	TYP	UNIT	
Input Capacitance	$C_{IN}$	—	3.3	TBD	pF	
Power Dissipation Capacitance	$C_{PD}$	$f_{IN} = 10\text{MHz}$	(Note 11)	3.3	TBD	pF

(Note 11)  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation :

$$I_{CC(\text{opr.})} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6 \text{ (Per gate)}$$

**TEST CIRCUIT**  
Fig.1



**AC WAVEFORM**  
Fig.2  $t_{pLH}$ ,  $t_{pHL}$

